

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microsemi.com

RADIATION HARDENED PNP SILICON SWITCHING TRANSISTOR

Qualified per MIL-PRF-19500/291

DEVICES

2N2906A 2N2907A 2N2906AL 2N2907AL 2N2906AUA 2N2907AUA 2N2906AUB 2N2907AUB 2N2906AUBC 2N2907AUBC

LEVELS

JANSM – 3K Rads (Si) JANSD – 10K Rads (Si) JANSP – 30K Rads (Si) JANSL – 50K Rads (Si) JANSR – 100K Rads (Si)

ABSOLUTE MAXIMUM RATINGS ($T_C = +25$ °C unless otherwise noted)

Parameters / Test Conditions	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	60	Vdc
Collector-Base Voltage	V _{CBO}	60	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector Current	I_{C}	600	mAdc
Total Power Dissipation @ T _A = +25°C	P _T (1)	0.5	W
Operating & Storage Junction Temperature Range	T _{op} , T _{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

Parameters / Test Conditions	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}^{~(1)}$	325	°C/W

^{1.} See MIL-PRF-19500/291 for derating curves.

ELECTRICAL CHARACTERISTICS ($T_A = +25$ °C, unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage $I_C = 10$ mAdc	V _{(BR)CEO}	60		Vdc
Collector-Base Cutoff Current $V_{CB} = 60 V dc$ $V_{CB} = 50 V dc$	I_{CBO}		10 10	μAdc ηAdc
$\begin{aligned} & \text{Emitter-Base Cutoff Current} \\ & V_{EB} = 5.0 \text{Vdc} \\ & V_{EB} = 4.0 \text{Vdc} \end{aligned}$	I_{EBO}		10 50	μAdc ηAdc
Collector-Emitter Cutoff Current $V_{CE} = 50Vdc$	I _{CES}		50	ηAdc



TO-18 (TO-206AA) 2N2906A, 2N2907A



4 PIN 2N2906AUA, 2N2907AUA



3 PIN 2N2906AUB, 2N2907AUB 2N2906AUBC, 2N2907AUBC (UBC = Ceramic Lid Version)

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ELECTRICAL CHARACTERISTICS ($T_A = +25$ °C, unless otherwise noted)

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
ON CHARACTERISTICS (2)					
Forward-Current Transfer Ratio					
$I_C = 0.1 \text{mAdc}, V_{CE} = 10 \text{Vdc}$	2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC		40 75		
$I_{C} = 1.0 \text{mAdc}, V_{CE} = 10 \text{Vdc}$	2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC		40 100	175 450	
$I_C = 10$ mAdc, $V_{CE} = 10$ Vdc	2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC	$ m h_{FE}$	40 100		
$I_C = 150$ mAdc, $V_{CE} = 10$ Vdc	2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC		40 100	120 300	
$I_{C} = 500 \text{mAdc}, V_{CE} = 10 \text{Vdc}$	2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC		40 50		
Collector-Emitter Saturation Voltage					
$\begin{split} I_{C} &= 150 \text{mAdc}, I_{B} = 15 \text{mAdc} \\ I_{C} &= 500 \text{mAdc}, I_{B} = 50 \text{mAdc} \end{split}$		V _{CE(sat)}		0.4 1.6	Vdc
Base-Emitter Voltage					
$\begin{split} I_{C} &= 150 \text{mAdc}, I_{B} = 15 \text{mAdc} \\ I_{C} &= 500 \text{mAdc}, I_{B} = 50 \text{mAdc} \end{split}$		V _{BE(sat)}	0.6	1.3 2.6	Vdc

DYNAMIC CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit	
Small-Signal Short-Circuit Forward Current Tra	nsfer Ratio				
$I_C = 1.0$ mAdc, $V_{CE} = 10$ Vdc, $f = 1.0$ kHz	2N2906A, L, UA, UB, UBC 2N2907A, L, UA, UB, UBC	${ m h_{fe}}$	40 100		
$\begin{aligned} & \text{Magnitude of Small-Signal Short-Circuit} \\ & \text{Forward Current Transfer Ratio} \\ & I_C = 20 \text{mAdc, } V_{CE} = 20 \text{Vdc, } f = 100 \text{MHz} \end{aligned}$		$ h_{\mathrm{fe}} $	2.0		
Output Capacitance $V_{CB} = 10 Vdc, I_E = 0, 100 kHz \le f \le 1.0 MHz$		C_{obo}		8.0	pF
$\label{eq:local_continuous_continuous} Input Capacitance $$ V_{EB} = 2.0Vdc, I_C = 0, 100kHz \le f \le 1.0MHz$		C_{ibo}		30	pF

SWITCHING CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Turn-On Time See MIL-PRF-19500/291	t _{on}		45	ηs
Turn-Off Time See MIL-PRF-19500/291	$t_{ m off}$		300	ηs

(2) Pulse Test: Pulse Width = $300\mu s$, Duty Cycle $\leq 2.0\%$.

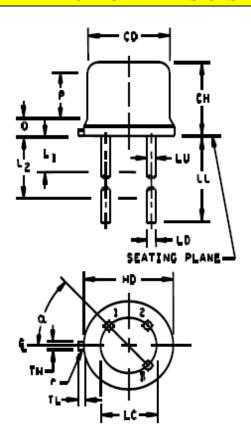
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PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Beyond r (radius) maximum, TW shall be held for a minimum length of .011 inch (0.28 mm).
- 4. Dimension TL measured from maximum HD.
- 5. Body contour optional within zone defined by HD, CD, and Q.
- 6. Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC.
- 7. Dimension LU applies between L_1 and L_2 . Dimension LD applies between L_2 and LL minimum. Diameter is uncontrolled in L_1 and beyond LL minimum.
- 8. All three leads.
- 9. The collector shall be internally connected to the case.
- 10. Dimension r (radius) applies to both inside corners of tab.
- 11. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.
- 12. Lead 1 = emitter, lead 2 = base, lead 3 = collector.
- 13. For L suffix devices, dimension LL = 1.5 inches (38.10 mm) min. and 1.75 inches (44.45 mm) max.

	Dimensions				
Symbol	Inc	Inches Millimet		neters	Note
	Min	Max	Min	Max	
CD	.178	.195	4.52	4.95	
CH	.170	.210	4.32	5.33	
HD	.209	.230	5.31	5.84	
LC	.100) TP	2.54	I TP	6
LD	.016	.021	0.41	0.53	7,8
LL	.500	.750	12.70	19.05	7,8,13
LU	.016	.019	0.41	0.48	7,8
L_1		.050		1.27	7,8
L_2	.250		6.35		7,8
P	.100		2.54		
Q		.030		0.76	5
TL	.028	.048	0.71	1.22	3,4
TW	.036	.046	0.91	1.17	3
r		.010		0.25	10
α	45°	TP	45° TP		6

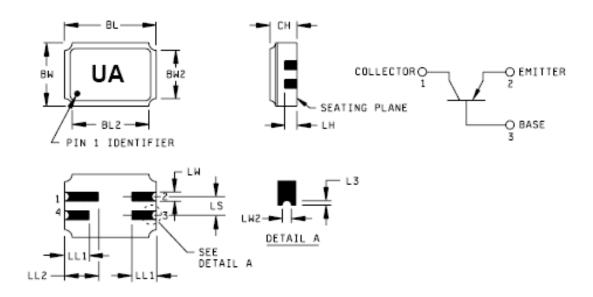
FIGURE 1. Physical dimensions (similar to TO-18)

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NOTES:

- 1. Dimensions are in inches.
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- 3. Dimension CH controls the overall package thickness. When a window lid is used, dimension CH must increase by a minimum of .010 inch (0.254 mm) and a maximum of .040 inch (1.020 mm).
- 4. The corner shape (square, notch, radius) may vary at the manufacturer's option, from that shown on the drawing.
- 5. Dimensions LW2 minimum and L3 minimum and the appropriate castellation length define an unobstructed three-dimensional space traversing all of the ceramic layers in which a castellation was designed. (Castellations are required on the bottom two layers, optional on the top ceramic layer.) Dimension "LW2" maximum and "L3" maximum define the maximum width and depth of the castellation at any point on its surface. Measurement of these dimensions may be made prior to solder dipping.
- 6. The co-planarity deviation of all terminal contact points, as defined by the device seating plane, shall not exceed .006 inch (0.15mm) for solder dipped leadless chip carriers.
- In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

	Dimensions				
Symbol	Inc	Inches Millimeters		Note	
	Min	Max	Min	Max	
BL	.215	.225	5.46	5.71	
BL2		.225		5.71	
BW	.145	.155	3.68	3.93	
BW2		.155		3.93	
CH	.061	.075	1.55	1.90	3
L3	.003	.007	0.08	0.18	5
LH	.029	.042	0.74	1.07	
LL1	.032	.048	0.81	1.22	
LL2	.072	.088	1.83	2.23	
LS	.045	.055	1.14	1.39	
LW	.022	.028	0.56	0.71	
LW2	.006	.022	0.15	0.56	5

Pin no.	1	2	3	4
Transistor	Collector	Emitter	Base	N/C

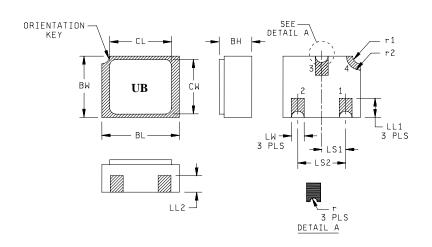
FIGURE 2. Physical dimensions, surface mount (UA version)

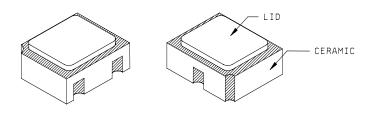
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Dimensions					
Symbol	Inc	hes	Milli	meters	Note
	Min	Max	Min	Max	
BH	.046	.056	1.17	1.42	
BL	.115	.128	2.92	3.25	
BW	.085	.108	2.16	2.74	
CL		.128		3.25	
CW		.108		2.74	
LL1	.022	.038	0.56	0.96	
LL2	.017	.035	0.43	0.89	

Symbol	Inc	hes	Millimeters		Note
	Min	Max	Min	Max	
LS_1	.036	.040	0.91	1.02	
LS_2	.071	.079	1.81	2.01	
LW	.016	.024	0.41	0.61	
r		.008		.203	
\mathbf{r}_1		.012		.305	
\mathbf{r}_2		.022		.559	

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Shielding connected to the lid.
- 4. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

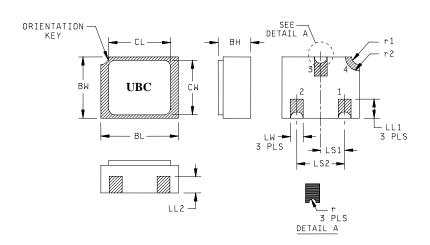
FIGURE 3. Physical dimensions, surface mount (UB version)

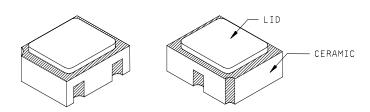
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Dimensions					
Symbol	Inc	Inches		Millimeters	
	Min	Max	Min	Max	
BH	.046	.071	1.17	1.80	
BL	.115	.128	2.92	3.25	
BW	.085	.108	2.16	2.74	
CL		.128		3.25	
CW		.108		2.74	
LL1	.022	.038	0.56	0.96	
LL2	.017	.035	0.43	0.89	

	Dimensions				
Symbol	Inches		Millimeters		Note
	Min	Max	Min	Max	
LS_1	.036	.040	0.91	1.02	
LS_2	.071	.079	1.81	2.01	
LW	.016	.024	0.41	0.61	
r		.008		.203	
\mathbf{r}_1		.012		.305	
\mathbf{r}_2		.022		.559	

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. Hatched areas on package denote metalized areas.
- 4. Pad 1 = Base, Pad 2 = Emitter, Pad 3 = Collector, Pad 4 = Connected to the lid braze ring.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

FIGURE 4. Physical dimensions, surface mount (UBC version, ceramic lid)

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